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Kind regards,

Team Nexperia

Product data sheet

1. Product profile

1.1 General description

Epitaxial medium-speed switching diode with a low leakage current, encapsulated in a small hermetically sealed glass SOD80C Surface-Mounted Device (SMD) package.

1.2 Features and benefits

- Continuous reverse voltage: max. 125 V
- Repetitive peak forward current: max. 625 mA
- Low reverse current: max. 1 nA
- Switching time: typ. 1.5 μs

1.3 Applications

Low leakage current applications

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		<u>[1]</u> _	-	250	mA
V _R	reverse voltage		-	-	125	V
V _F	forward voltage	$I_F = 100 \text{ mA}$	-	-	1000	mV

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode	<u>[1]</u>	
2	anode	k a	1 2 006aab040

^[1] The marking band indicates the cathode.



3. Ordering information

Table 3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
BAS45AL	-	hermetically sealed glass surface-mounted package; 2 connectors	SOD80C				

4. Marking

Table 4. Marking codes

Type number	Marking code
BAS45AL	marking band

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	125	V
V_R	reverse voltage		-	125	V
I _F	forward current		<u>[1]</u> _	250	mA
I _{FRM}	repetitive peak forward current		-	625	mA
I _{FSM}	non-repetitive peak forward current	square wave	<u>[2]</u>		
		$t_p = 1 \mu s$	-	4	Α
		$t_p = 1 \text{ ms}$	-	1	Α
		$t_p = 1 s$	-	0.5	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> _	400	mW
Tj	junction temperature		-	175	°C
T _{stg}	storage temperature		-65	+175	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] $T_j = 25$ °C prior to surge.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-t)}$	thermal resistance from junction to tie-point		-	-	300	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	375	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

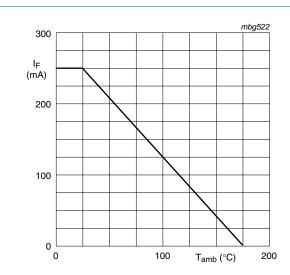
7. Characteristics

Table 7. Characteristics

 $T_i = 25$ °C unless otherwise specified.

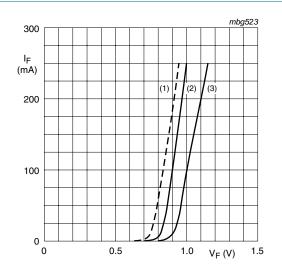
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F forw	forward voltage	$I_F = 1 \text{ mA}$	-	-	780	mV
		I _F = 10 mA	-	-	860	mV
		I _F = 100 mA	-	-	1000	mV
I _R reverse	reverse current	$E_{\text{max}} = 100 \text{ lx}$				
		V _R = 125 V	-	-	1	nA
		$V_R = 30 \text{ V}; T_j = 125 ^{\circ}\text{C}$	-	-	300	nA
		V _R = 125 V; T _j = 125 °C	-	-	500	nA
		V _R = 125 V; T _j = 150 °C	-	-	2	μΑ
C _d	diode capacitance	$V_R = 0 V$; $f = 1 MHz$	-	-	4	pF
t _{rr}	reverse recovery time		<u>[1]</u> _	1.5	-	μs

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.



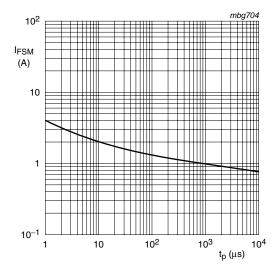
FR4 PCB, standard footprint

Fig 1. Forward current as a function of ambient temperature; derating curve



- (1) T_j = 150 °C; typical values
- (2) $T_i = 25 \,^{\circ}C$; typical values
- (3) $T_j = 25 \,^{\circ}C$; maximum values

Fig 2. Forward current as a function of forward voltage



Based on square wave currents.

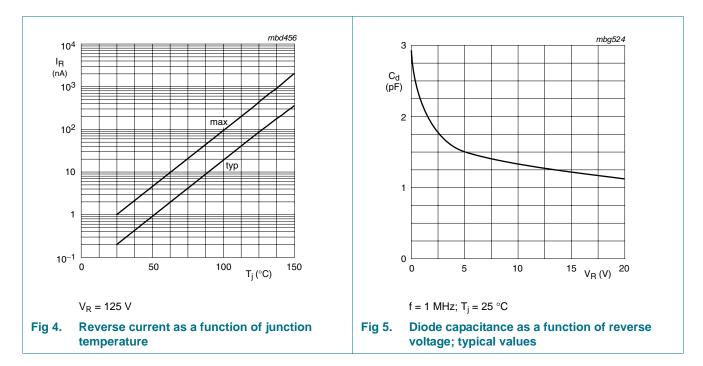
 $T_j = 25$ °C prior to surge

Fig 3. Non-repetitive peak forward current as a function of pulse duration; maximum values

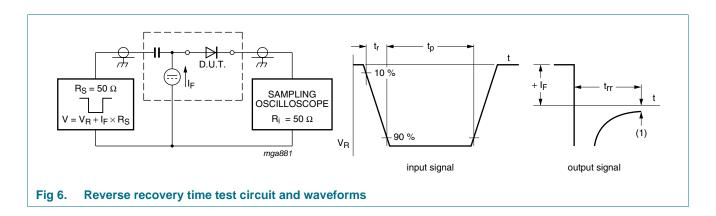
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BAS45AL

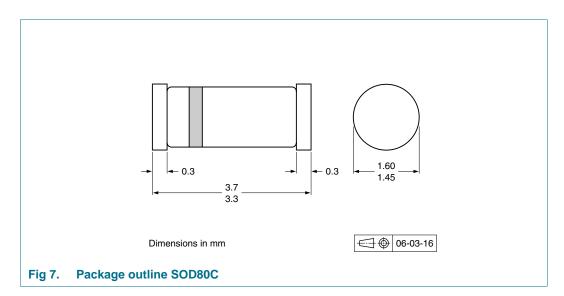
Low-leakage diode



8. Test information



9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

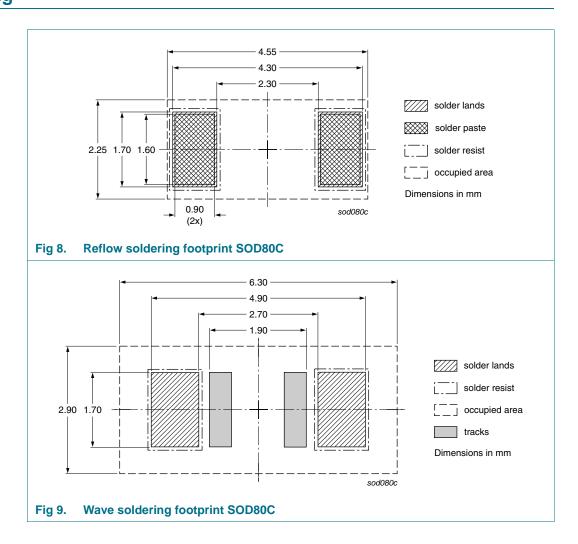
Type number	Package	Description	Packing quantity	
			2500	10000
BAS45AL	SOD80C	4 mm pitch, 8 mm tape and reel	-115	-135

^[1] For further information and the availability of packing methods, see Section 14.

BAS45AL

Low-leakage diode

11. Soldering



12. Revision history

Table 9. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS45AL v.5	20100806	Product data sheet	-	BAS45AL_4
Modifications:		f this data sheet has been red NXP Semiconductors.	esigned to comply w	ith the new identity
	 Legal texts h 	ave been adapted to the new	company name whe	re appropriate.
	 Table 1 "Quid 	ck reference data": added		
	 Section 4 "M 	arking": added		
	• Figure 7: sup	erseded by minimized packag	e outline drawing	
	 Section 10 "F 	Packing information": added		
	Section 11 "S	Soldering": added		
	 Section 13 "L 	egal information": updated		
BAS45AL_4	19990528	Product specification	-	BAS45AL_3
BAS45AL_3	19990504	Product specification	-	BAS45AL_2
BAS45AL_2	19960313	Product specification	-	BAS45AL_1

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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NXP Semiconductors BAS45AL

Low-leakage diode

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